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Linwave QFN 2-18 GHz LNA

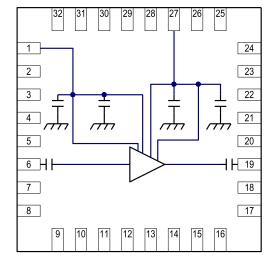




Applications:

- Communications systems
- Low noise receivers

Functional Diagram:



Features:

- Frequency from 2-18GHz
- Nominal gain: 24dB
- Low Noise Figure <2.5dB, typically 2.1dB
- TOIP typically +25dBm
- Quiescent bias Vd=4V, Id=120mA
- QFN
- Integrated DC blocks

General Description:

The LW48-793135 provides an easy to use LNA with a low noise figure across a wide bandwidth. Its high performance makes it versatile and suitable for both commercial and military use.

| Pin Designations | | | | |
|------------------|----------|--|--|--|
| Pin No. | Function | | | |
| Pin 6 | RF IN | | | |
| Pin 19 | RF OUT | | | |
| Pin 2-5, 7-8 | GROUND | | | |
| Pin 17-18, 20-24 | GROUND | | | |
| Pin 27 | Vd1 | | | |
| Pin 1 | Vg1 | | | |

Linwave reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance.

Data sheet Iss 01, dated 25/02/15 DS00-793135-01, No. 2144

For price, delivery and to place orders please contact
Linwave Technology Ltd, Marlin Building, Sadler Road, Lincoln, LN6 3RS
Company Reg No 4478971 (England)
Phone:+44 (0) 1522 681811 Fax:+44 (0) 1522 681911
Email enquiries@linwave.co.uk
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Electrical Specifications Vdd=3.0V Vg=1.5V T=25 °C

| Parameter | Min | Тур | Max | Units |
|--------------------|-----|-----|-----|-------|
| Frequency Range | 2 | | 18 | GHz |
| | | | | |
| Gain | | 24 | | dB |
| Noise Figure | | 2 | | dB |
| Input Return Loss | | | | dB |
| 2-16GHz | | 8 | | |
| 16-18GHz | | 4 | | |
| | | | | |
| Output Return Loss | | 12 | | dB |
| | | | | |
| Output P1dB | | 15 | | dBm |
| Supply Current | | 120 | | mA |

Recommended Operating Conditions

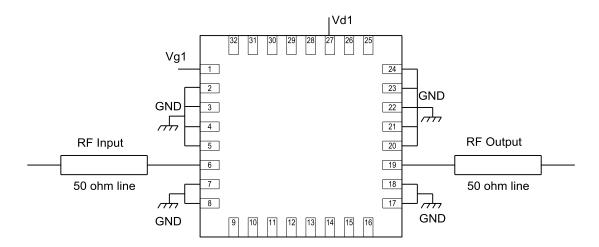
| Parameter | Min | Тур | Max | Units |
|-----------|-----|-------|-----|-------|
| Vdd | | 4 | | V |
| ld1,2 | | 120 | | mA |
| Vg1,2 | | -0.45 | | V |

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Application Circuit

Note: Effective heatsinking through the ground paddle on the underside of the package is essential for high power operation (RF Input >1W)



Bias Up: Ensure gate voltage is set to -1.8V, apply drain voltage, decrease Vg until the drain current is 120mA.

Bias Down: Ensure gate voltage is set to -1.8V, remove drain bias, remove gate bias

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